

Contents

Series Preface	xiii
Preface	xv
1 Charge Transport via Delocalized States in Disordered Materials	1
<i>Igor Zvyagin</i>	
1.1 Introduction	2
1.2 Transport by Electrons in Extended States Far from the Mobility Edges	4
1.2.1 Weak-scattering theories	4
1.2.2 Weak localization	10
1.2.3 Interaction effects	12
1.3 Scaling Theory of Localization	14
1.3.1 Main ideas of the scaling theory of localization	14
1.3.2 The main equations of one-parameter scaling	15
1.3.3 Model solutions	18
1.3.4 Some predictions of the scaling theory	22
1.3.5 Minimum metallic conductivity	24
1.4 Extended-state Conduction in Three Dimensions	26
1.4.1 Activated conduction	26
1.4.2 Extended-state conduction near the metal–insulator transition	28
1.5 Apparent Mobility Edge and Extended-state Conduction in Two-dimensional Systems	33
1.5.1 Experimental studies of the mobility edge in low-mobility two-dimensional systems	33
1.5.2 Evidence for a true metal–insulator transition in high-mobility two-dimensional systems	34
1.5.3 Evidence against a true metal–insulator transition in two-dimensional systems	37
1.5.4 Temperature-dependent charge carrier scattering	38
1.6 Conclusions	43
References	44
2 Description of Charge Transport in Amorphous Semiconductors	49
<i>Sergei Baranovski and Oleg Rubel</i>	
2.1 Introduction	49
2.2 General Remarks on Charge Transport in Disordered Materials	51

2.3	Hopping Charge Transport in Disordered Materials via Localized States	55
2.3.1	Nearest-neighbor hopping	57
2.3.2	Variable-range hopping	60
2.4	Description of Charge-carrier Energy Relaxation and Hopping Conduction in Inorganic Noncrystalline Materials	63
2.4.1	Dispersive transport in disordered materials	64
2.4.2	The concept of the transport energy	69
2.5	Einstein's Relationship for Hopping Electrons	73
2.5.1	Nonequilibrium charge carriers	73
2.5.2	Equilibrium charge carriers	75
2.6	Steady-state Photoconductivity	76
2.6.1	Low-temperature photoconductivity	77
2.6.2	Temperature dependence of the photoconductivity	81
2.7	Thermally Stimulated Currents—a Tool to Determine DOS?	83
2.8	Dark Conductivity in Amorphous Semiconductors	87
2.9	Nonlinear Field Effects	90
2.10	Concluding Remarks	93
	References	93
3	Hydrogenated Amorphous Silicon—Material Properties and Device Applications	97
	<i>Walther Fuhs</i>	
3.1	Introduction	97
3.2	Preparation and Structural Properties of Amorphous Silicon	99
3.3	Density of States Distribution in the Energy Gap	104
3.3.1	Model of the density of states distribution	104
3.3.2	Band-tail states	105
3.3.3	Deep defect states	107
3.4	Optical Properties	113
3.5	Transport Properties	115
3.6	Recombination of Excess Carriers	121
3.6.1	Low-temperature regime ($T < 60$ K)	122
3.6.2	High-temperature regime ($T > 60$ K)	127
3.7	Device Applications	130
3.7.1	Schottky barrier diodes	131
3.7.2	$p-i-n$ diodes	132
3.7.3	Thin-film transistors	134
3.8	Thin-film Solar Cells	137
	References	143
4	Applications of Disordered Semiconductors in Modern Electronics: Selected Examples	149
	<i>Safa Kasap, John Rowlands, Kenkichi Tanioka and Arokia Nathan</i>	
4.1	Perspectives on Amorphous Semiconductors	149
4.2	Direct Conversion Digital X-ray Image Detectors	151

4.3 X-ray Photoconductors	152
4.4 Stabilized Amorphous Selenium (<i>a</i> -Se)	154
4.5 Avalanche Multiplication and Ultra-high-sensitive HARP Video Tube	157
4.6 Avalanche Multiplication in Amorphous Semiconductors	160
4.7 Future Imaging Applications with <i>a</i> -Se HARP	165
4.8 Hydrogenated Amorphous Silicon Thin-film Transistors	167
4.9 TFT Backplanes for Organic Light-emitting Diode Displays and Flat-panel X-ray Imagers	170
4.9.1 Active matrix organic light-emitting diode displays	170
4.9.2 Active pixel sensors for digital fluoroscopy	173
References	175
5 The Investigation of Charge Carrier Recombination and Hopping Transport with Pulsed Electrically Detected Magnetic Resonance Techniques	179
<i>Christoph Boehme and Klaus Lips</i>	
5.1 Introduction	180
5.2 Spin-dependent Recombination	182
5.3 Spin-dependent Hopping Transport	189
5.4 The Theory of a pEDMR Experiment	194
5.4.1 Rabi oscillation and the discrimination of spin coupling	195
5.4.2 Recombination and hopping echoes and the determination of transitions times	198
5.5 Experimental Foundations of Pulsed EDMR	200
5.5.1 Current detection	201
5.5.2 Sample design	202
5.5.3 Microwave-induced currents	204
5.5.4 Limitations of pEDMR experiments	206
5.6 PEDMR on Transport Channels Through <i>n</i> - <i>a</i> -Si:H	206
5.6.1 Detection of transport transitions	207
5.6.2 Observation of Rabi oscillation	209
5.6.3 Coherence decay and hopping times	211
5.7 Discussion of the Experimental Results	213
5.8 Conclusions	215
5.9 Summary	217
References	218
6 Description of Charge Transport in Disordered Organic Materials	221
<i>Sergei Baranovski and Oleg Rubel</i>	
6.1 Introduction	222
6.2 Characteristic Experimental Observations and the Model for Charge Carrier Transport in Random Organic Semiconductors	224
6.3 Energy Relaxation of Charge Carriers in a Gaussian DOS. Transition from Dispersive to Nondispersive Transport	228
6.4 Theoretical Treatment of Charge Carrier Transport in Random Organic Semiconductors	230

6.4.1	Averaging of hopping rates	230
6.4.2	Percolation approach	233
6.4.3	Transport energy for a Gaussian DOS	233
6.4.4	Calculations of τ_{rel} and μ	235
6.4.5	Saturation effects	241
6.5	Theoretical Treatment of Charge Carrier Transport in One-dimensional Disordered Organic Systems	243
6.5.1	General analytical formulas	245
6.5.2	Drift mobility in the random-barrier model	246
6.5.3	Drift mobility in the Gaussian disorder model	248
6.5.4	Mesoscopic effects for the drift mobility	251
6.5.5	Drift mobility in the random-energy model with correlated disorder (CDM)	253
6.5.6	Hopping in 1D systems: beyond the nearest-neighbor approximation	254
6.6	On the Relation Between Carrier Mobility and Diffusivity in Disordered Organic Systems	255
6.7	On the Description of Coulomb Effects caused by Doping in Disordered Organic Semiconductors	258
6.8	Concluding remarks	262
	References	263
7	Device Applications of Organic Materials	267
	<i>Elizabeth von Hauff, Carsten Deibel and Vladimir Dyakonov</i>	
7.1	Introduction	267
7.2	Charge Transport in Disordered Organic Semiconductors	268
7.2.1	Electrical conduction in carbon-based materials	269
7.2.2	Hopping transport	270
7.2.3	Injection into organic semiconductors	270
7.2.4	Space-charge-limited currents	272
7.2.5	Charge carrier mobility	273
7.3	Experimental Characterization of Charge Transport Properties	275
7.3.1	Time-of-flight transient photoconductivity	276
7.3.2	Charge extraction by linearly increasing voltage	278
7.3.3	Current–voltage measurements	279
7.3.4	Field-effect transistor measurements	280
7.4	Advances in Organic Electronics	285
7.4.1	Device fabrication	285
7.4.2	Organic light-emitting diodes	286
7.4.3	Organic field-effect transistors	288
7.4.4	Organic memory	290
7.4.5	Organic photovoltaics	291
7.4.6	Organic lasers	296
7.5	Conclusions	297
	References	297

8 Generation, Recombination and Transport of Nonequilibrium Carriers in Polymer–Semiconductor Nanocomposites	307
<i>H.E. Ruda and Alexander Shik</i>	
8.1 Introduction	307
8.2 Basic Features of Polymer–Semiconductor Nanocomposites	308
8.3 Energy Band Diagram and Optical Absorption	309
8.4 Excitons	312
8.5 Potential Relief at High Excitation Level	314
8.6 Photoconductivity	318
8.7 Photoluminescence	319
8.7.1 Luminescence spectrum and Stokes shift	319
8.7.2 Exciton capture by NCs	320
8.8 Diode Nanocomposite Structures	325
8.9 Carrier Capture by Nanocrystals in an External Electric Field	326
8.10 Theory of Nanocomposite Light Emitters	328
8.10.1 Basic equations	328
8.10.2 Current–voltage characteristic	329
8.10.3 Quantum yield of NC electroluminescence	330
8.11 Electro–Luminescence vs Photoluminescence	333
8.12 Polymer–Dielectric Nanocomposites	334
8.13 Concluding Comments	334
References	335
9 AC Hopping Transport in Disordered Materials	339
<i>Igor Zvyagin</i>	
9.1 Introduction	339
9.2 Universality and Scaling	343
9.3 Phononless AC Conductivity	346
9.4 Phonon-assisted AC Conductivity in the Pair Approximation	350
9.4.1 Model	350
9.4.2 AC conductivity for noninteracting electrons in the pair approximation	353
9.4.3 Pair approximation for interacting electrons	355
9.4.4 Crossover from phonon-assisted to phononless regime	356
9.4.5 Different tunneling mechanisms	356
9.5 Multiple Hopping Regime	357
9.5.1 Frequency-dependent cluster construction	357
9.5.2 AC current and conductivity	359
9.5.3 Frequency range for the multiple hopping regime	360
9.6 Classical hopping	363
9.6.1 Pike’s model	363
9.6.2 Random barrier models for ionic conduction	365
9.6.3 Nearly constant loss	368
9.7 Conclusions	369
Appendix 9.1 Frequency Response of a Finite Isolated Cluster	371

Appendix 9.2 Size Distribution of Finite Clusters	374
References	375
10 Mechanisms of Ion Transport in Amorphous and Nanostructured Materials	379
<i>Bernhard Roling</i>	
10.1 Introduction	380
10.2 Prerequisites for Ionic Conduction in Solids	381
10.3 Glasses	382
10.3.1 Spatial extent of subdiffusive ion dynamics	382
10.3.2 Dynamic heterogeneities probed by multidimensional NMR techniques	384
10.3.3 New information about ion transport pathways from reverse Monte Carlo modeling and bond valence calculations	384
10.3.4 New information about empty sites and transport mechanisms from molecular dynamics simulations	385
10.3.5 Field-dependent conductivity of thin glass samples	386
10.4 Amorphous Polymer Electrolytes	388
10.4.1 Salt-in-polymer electrolytes	388
10.4.2 Gel electrolytes	390
10.4.3 Polymer-in-salt electrolytes	390
10.4.4 'Hairy-rod' polymer electrolytes	391
10.5 Nanocrystalline Materials and Composites	392
10.6 Heterostructures	393
10.7 Nano- and Mesostructured Glass Ceramics	393
10.8 Nanocomposite and Nanogel Electrolytes	396
10.9 Hybrid Electrolytes	398
10.10 Summary and Conclusions	398
References	400
11 Applications of Ion Transport in Disordered Solids: Electrochemical Micro-ionics	403
<i>Philippe Vinatier and Yohann Hamon</i>	
11.1 Introduction	403
11.2 Materials and Ionic Conductivity	405
11.2.1 Glasses	405
11.2.2 Ionic conductivity in glasses	408
11.2.3 Thin-film preparation	409
11.3 Lithium-ion-conducting Oxide Glasses in Micro-sources of Power	411
11.3.1 Principle of lithium microbatteries and related systems	411
11.3.2 Requirements of thin-film electrolytes for electrochemical microsystems	413
11.3.3 Electrolyte materials used in electrochemical microsystems	414
11.3.4 Resulting devices	417
11.4 Silver-ion-conducting Chalcogenide Glasses in Solid-state Ionic Memories and Sensors	418

11.4.1 Solid-state ionic memory	418
11.4.2 Sensors	422
11.5 Conclusions	426
References	426
12 DNA Conduction: the Issue of Static Disorder, Dynamic Fluctuations and Environmental Effects	433
<i>Rafael Gutiérrez, Danny Porath and Gianarelio Cuniberti</i>	
12.1 Introduction	433
12.2 Charge Transport Experiments in DNA Oligomers	436
12.2.1 Single-molecule transport experiments	438
12.2.2 Transport experiments on bundles and networks	449
12.3 Theoretical Aspects of DNA Conduction	453
12.3.1 Static disorder	453
12.3.2 Dynamical disorder	454
12.3.3 Environmental effects	456
12.4 Conclusions	459
References	460
Index	465

